

T493B475K010CT6110

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 4.7 uF, 10%, 10 VDC, SMD, MnO2, Molded, High Reliability, C (0.01%/1000 Hrs), 3.5 Ohms, 3528, 2.1 mm, 0.8 mm

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



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General Information

Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, High Reliability
Features	High Reliability
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	102.3 mg
Notes	P and R dimensions represents the minimum solderable area of the termination surface entirely below cutout (if one is present).

Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
T	0.13mm REF
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
B	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
P	0.35mm MIN
R	1mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

Specifications

Capacitance	4.7 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	C (0.01%/1000 Hrs)
ESR	3.5 Ohms (100kHz 25C)
Ripple Current	156 mA (rms, 100kHz 25C)
Leakage Current	0.5 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

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